



# PJS6415AE

## 20V P-Channel Enhancement Mode MOSFET – ESD Protected

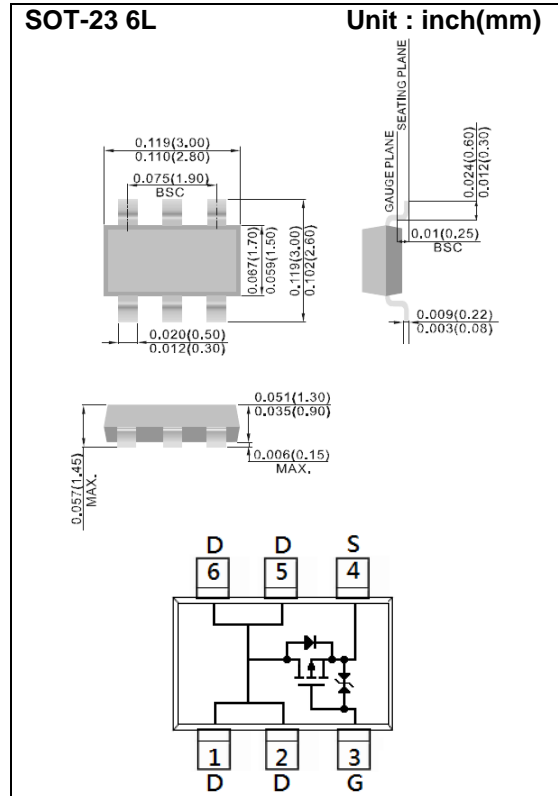
**Voltage**    **-20 V**    **Current**    **-4.9A**

### Features

- RDS(ON) , VGS@-10V, ID@-4.9A<60mΩ
- RDS(ON) , VGS@-4.5V, ID@-4.2A<70mΩ
- RDS(ON) , VGS@-2.5V, ID@-3.1A<96mΩ
- Advanced Trench Process Technology
- Specially Designed for Switch Load, PWM Application, etc
- ESD Protected 2KV HBM
- Lead free in compliance with EU RoHS 2.0
- Green molding compound as per IEC 61249 standard

### Mechanical Data

- Case: SOT-23 6L Package
- Terminals : Solderable per MIL-STD-750, Method 2026
- Approx. Weight: 0.0003 ounces, 0.0084 grams
- Marking: S5E



## Maximum Ratings and Thermal Characteristics (T<sub>A</sub>=25°C unless otherwise noted)

PARAMETER		SYMBOL	LIMIT	UNITS
Drain-Source Voltage		V <sub>DS</sub>	-20	V
Gate-Source Voltage		V <sub>GS</sub>	±12	V
Continuous Drain Current		I <sub>D</sub>	-4.9	A
Pulsed Drain Current		I <sub>DM</sub>	-19.6	A
Power Dissipation	T <sub>a</sub> =25°C	P <sub>D</sub>	2	W
	Derate above 25°C		16	mW/°C
Operating Junction and Storage Temperature Range		T <sub>J</sub> , T <sub>STG</sub>	-55~150	°C
Typical Thermal resistance		R <sub>θJA</sub>	62.5	°C/W
- Junction to Ambient <sup>(Note 3)</sup>				



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## Electrical Characteristics ( $T_A=25^\circ\text{C}$ unless otherwise noted)

PARAMETER	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNITS
<b>Static</b>						
Drain-Source Breakdown Voltage	$BV_{DSS}$	$V_{GS}=0V, I_D=-250\mu A$	-20	-	-	V
Gate Threshold Voltage	$V_{GS(th)}$	$V_{DS}=V_{GS}, I_D=-250\mu A$	-0.5	-0.77	-1.2	V
Drain-Source On-State Resistance	$R_{DS(on)}$	$V_{GS}=-10V, I_D=-4.9A$	-	50	60	mΩ
		$V_{GS}=-4.5V, I_D=-4.2A$	-	58	70	
		$V_{GS}=-2.5V, I_D=-3.1A$	-	80	96	
		$V_{GS}=-1.8V, I_D=-0.5A$	-	140	180	
Zero Gate Voltage Drain Current	$I_{DSS}$	$V_{DS}=-20V, V_{GS}=0V$	-	-0.01	-1	μA
Gate-Source Leakage Current	$I_{GSS}$	$V_{GS}=\pm 8V, V_{DS}=0V$	-	$\pm 6$	$\pm 10$	μA
<b>Dynamic</b> (Note 5)						
Total Gate Charge	$Q_g$	$V_{DS}=-10V, I_D=-4.9A,$ $V_{GS}=-4.5V$ (Note 1,2)	-	6.9	-	nC
Gate-Source Charge	$Q_{gs}$		-	1.5	-	
Gate-Drain Charge	$Q_{gd}$		-	1.9	-	
Input Capacitance	$C_{iss}$	$V_{DS}=-10V, V_{GS}=0V,$ $f=1.0\text{MHZ}$	-	602	-	pF
Output Capacitance	$C_{oss}$		-	70	-	
Reverse Transfer Capacitance	$C_{rss}$		-	47	-	
Turn-On Delay Time	$t_{d(on)}$	$V_{DD}=-10V, I_D=-4.9A,$ $V_{GS}=-4.5V,$ $R_G=3\Omega$ (Note 1,2)	-	8.8	-	ns
Turn-On Rise Time	$t_r$		-	66	-	
Turn-Off Delay Time	$t_{d(off)}$		-	29	-	
Turn-Off Fall Time	$t_f$		-	14	-	
<b>Drain-Source Diode</b>						
Maximum Continuous Drain-Source Diode Forward Current	$I_S$	---	-	-	-1.5	A
Diode Forward Voltage	$V_{SD}$	$I_S=-1.0A, V_{GS}=0V$	-	-0.79	-1.0	V

**NOTES :**

1. Pulse width  $\leq 300\mu s$ , Duty cycle  $\leq 2\%$
2. Essentially independent of operating temperature typical characteristics.
3.  $R_{\theta JA}$  is the sum of the junction-to-case and case-to-ambient thermal resistance where the case thermal reference is defined as the solder mounting surface of the drain pins mounted on a 1 inch FR-4 with 2oz. square pad of copper
4. The maximum current rating is package limited
5. Guaranteed by design, not subject to production testing



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## TYPICAL CHARACTERISTIC CURVES

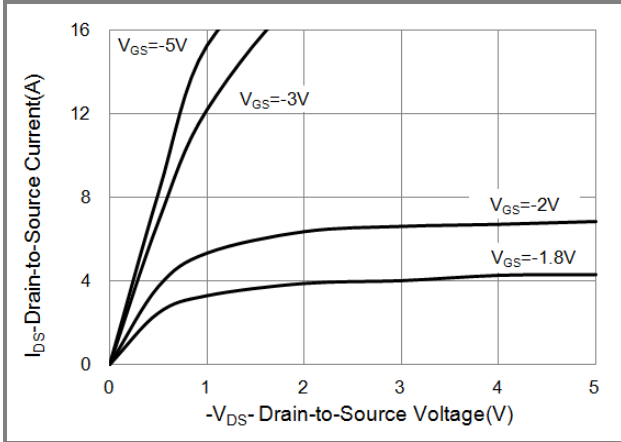


Fig.1 On-Region Characteristics

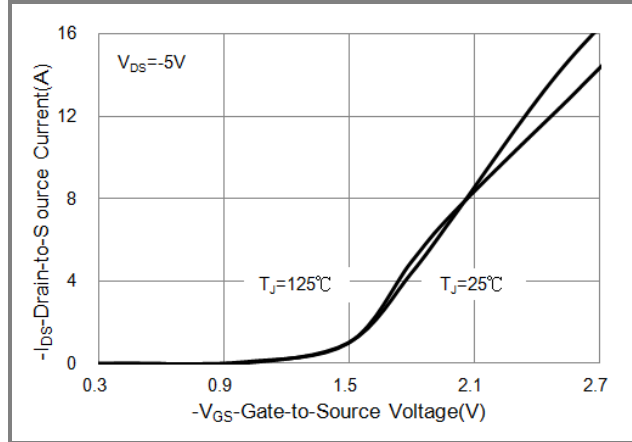


Fig.2 Transfer Characteristics

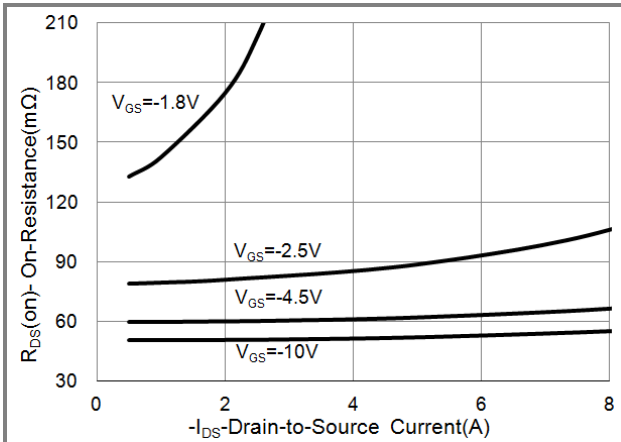


Fig.3 On-Resistance vs. Drain Current

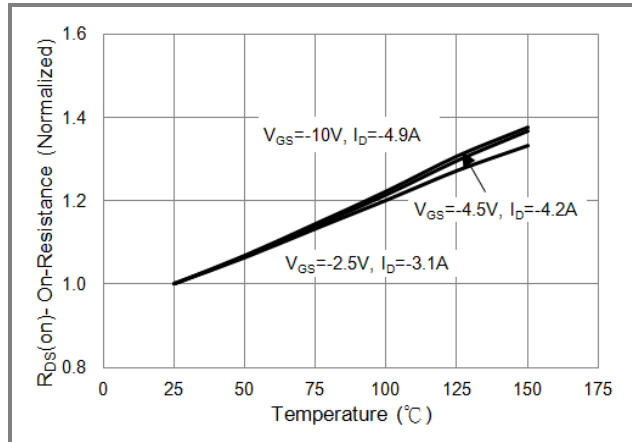


Fig.4 On-Resistance vs. Junction temperature

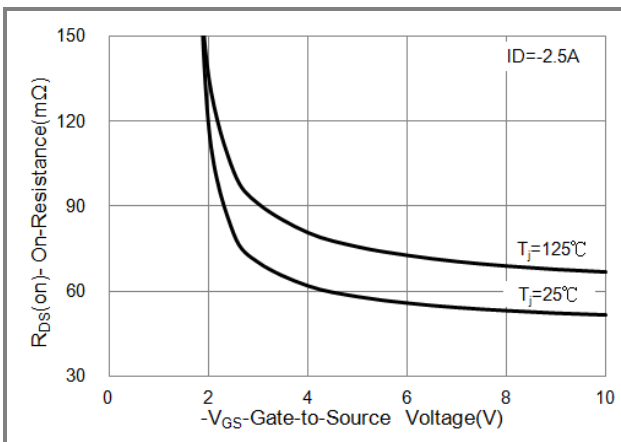


Fig.5 On-Resistance Variation with VGS.

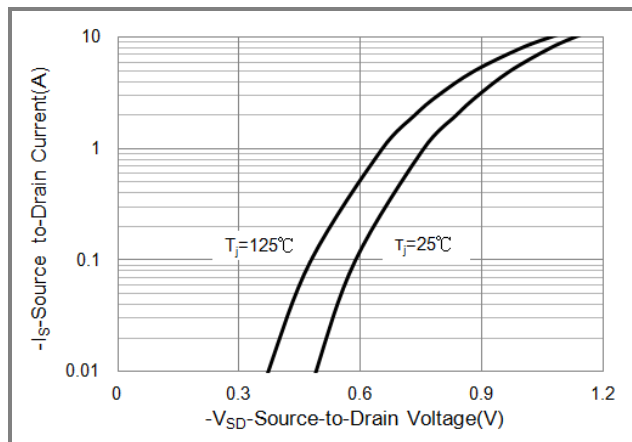


Fig.6 Body Diode Characteristics



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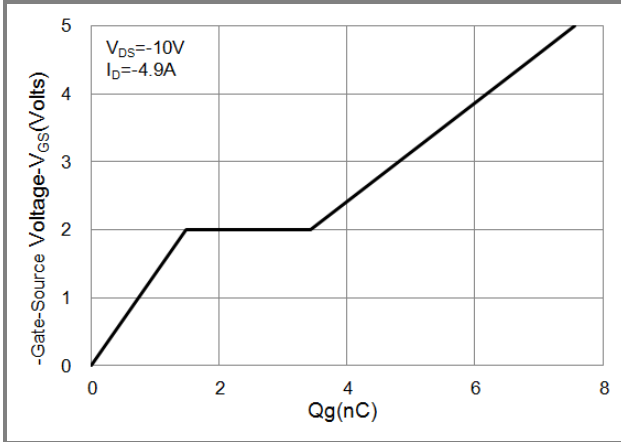


Fig.7 Gate-Charge Characteristics

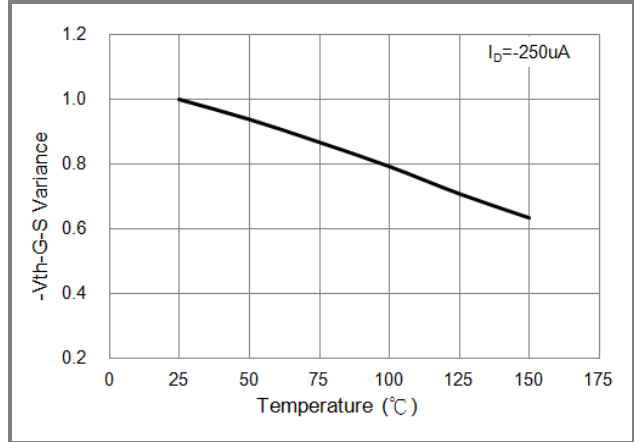


Fig.8 Threshold Voltage Variation with Temperature.

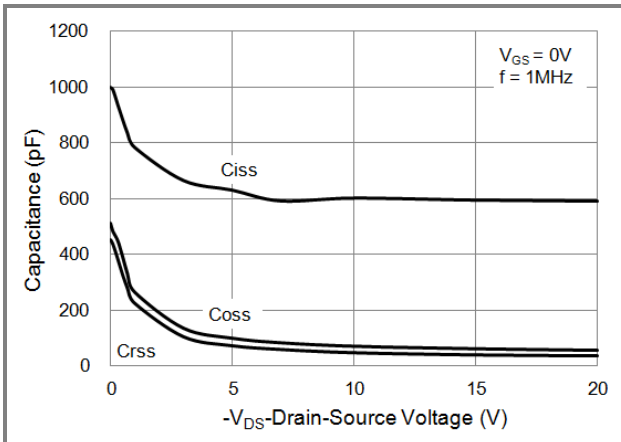


Fig.9 Capacitance vs. Drain-Source Voltage.

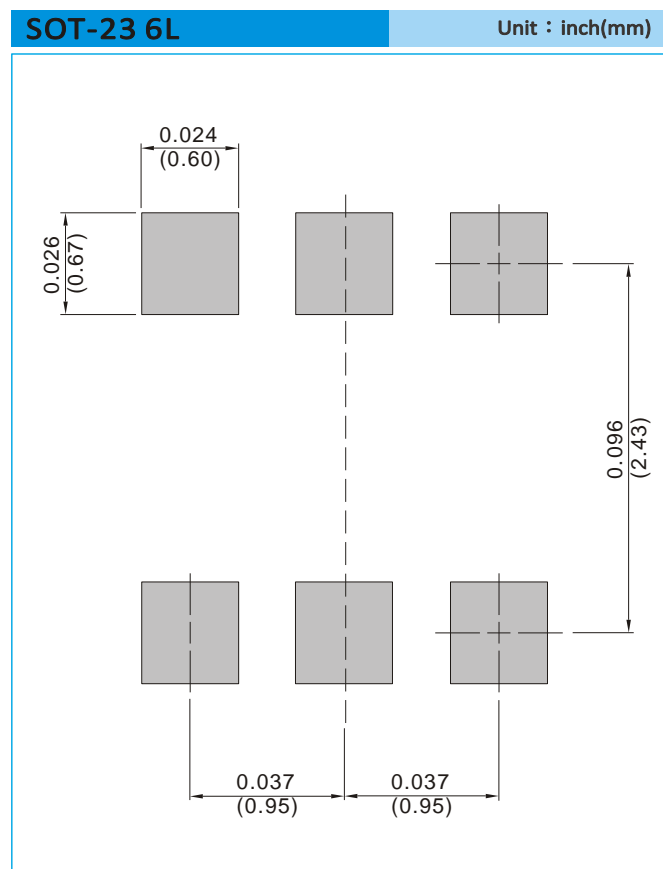


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## PART NO PACKING CODE VERSION

Part No Packing Code	Package Type	Packing Type	Marking	Version
PJS6415AE_S1_00001	SOT-23 6L	3K pcs / 7" reel	S5E	Halogen free
PJS6415AE_S2_00001	SOT-23 6L	10K pcs / 13" reel	S5E	Halogen free

## MOUNTING PAD LAYOUT





## PJS6415AE

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